

Features

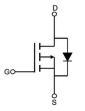
-100V,-18A

$$\begin{split} R_{DS~(ON)} < &112 m\Omega~@V_{GS} = -10V~TYP:~86 m\Omega \\ R_{DS~(ON)} < &120 m\Omega~@V_{GS} = -4.5V~TYP:~90 m\Omega \end{split}$$

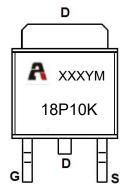
- Low Gate Charge
- 100% UIS Tested, 100% DVDS Tested
- High Power and current handing capability
- Lead free product is acquired

Applications

- Battery management
- Motor control and drive
- UPS (Uninterrupible Power Supplies)



Schematic Diagram



Marking and pin assignment

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
18P10K	AP18P10K	TO-252	-	-	2500

ABSOLUTE MAXIMUM RATINGS (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-100	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current (Tc=25°C)	I _D	-18	Α
Continuous Drain Current (Tc=100°C)	I _D	-12.5	A
Pulsed Drain Current (1)	I _{DM}	-72	А
Drain Power Dissipation	P _D	79	W
Single Pulsed Avalanche Energy ⁽²⁾	E _{AS}	156	mJ
Thermal Resistance from Junction to Case	Rejc	1.9	°C/W
Thermal Resistance from Junction to Ambient	R _{θJA}	91	°C/W
Junction Temperature	TJ	-55~ +175	$^{\circ}\!\mathbb{C}$
Storage Temperature	T _{STG}	-55~ +175	$^{\circ}$ C





MOSFET ELECTRICAL CHARACTERISTICS(TJ=25℃ unless otherwise noted)

Parameter	Symbol Test Condition		Min	Туре	Max	Unit	
Static Characteristics							
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250µA	-100	-	-	V	
Zero gate voltage drain current	I _{DSS}	V _{DS} =-100V, V _{GS} = 0V	-	-	-1	μA	
Gate-body leakage current	I _{GSS}	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	-	-	±100	nA	
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1.0	-	-2.5	V	
Drain-source on-resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	86	112	mΩ	
Drain-source on-resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-8A	-	90	120	mΩ	
Dynamic characteristics							
Input Capacitance	C _{iss}		-	3769	-	pF	
Output Capacitance	Coss	V _{DS} =-50V, V _{GS} =0V, f=1MHz	-	72	-		
Reverse Transfer Capacitance	C _{rss}	-	-	66	-		
Switching characteristics							
Turn-on delay time	t _{d(on)}		-	11.6	-	ns ns	
Turn-on rise time	t _r	V_{DD} =-50V, I_{D} =-10A, R_{G} =9.1 Ω ,	-	18	-		
Turn-off delay time	t _{d(off)}	V _{GS} =-10V	-	115	-		
Turn-off fall time	t _f		-	42	-		
Total Gate Charge	Qg	V 50V L 40A	-	72	-		
Gate-Source Charge	Qgs	V _{DS} =-50V, I _D =-10A,	-	8.4	-	nC	
Gate-Drain Charge	Qgd	- V _{GS} =-10V	-	17.5	-		
Source-Drain Diode characteristics							
Diode Forward voltage ⁽³⁾	V _{SD}	T _J =25°C, V _{GS} =0V, I _S =-10A	-	-	-1.2	V	
Diode Forward current	Is	T _C =25℃	-	-	-18	Α	
Body Diode Reverse Recovery Time	trr	- T _J =25℃, I _F =-10A,di/dt=100A/us	-	45	-	ns	
Body Diode Reverse Recovery Charge	Qrr	1 J-23 C, IF10A,ul/ul-100A/us	-	99	-	nC	

Notes:

^{1.}Repetitive Rating: Pulse width limited by maximum junction temperature.

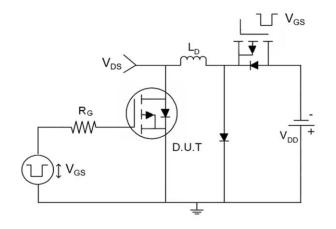
^{2.}E_{AS} condition: T_J =25°C, V_{DD} =50V, V_G =-10V, Rg=25 Ω , L=0.5mH.

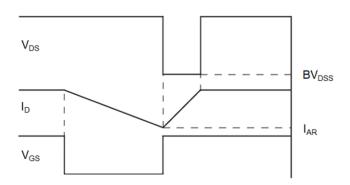
^{3.}Repetitive Rating: Pulse width limited by maximum junction temperature.



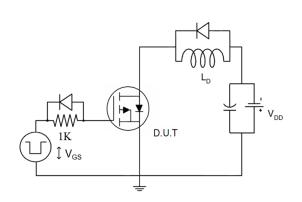
Test Circuit

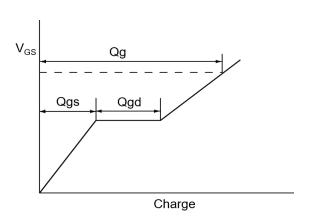
1) E_{AS} Test Circuits



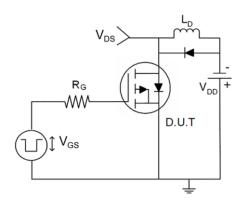


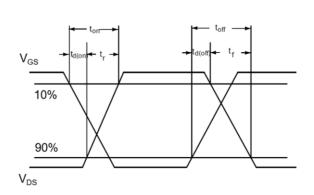
2) Gate Charge Test Circuit





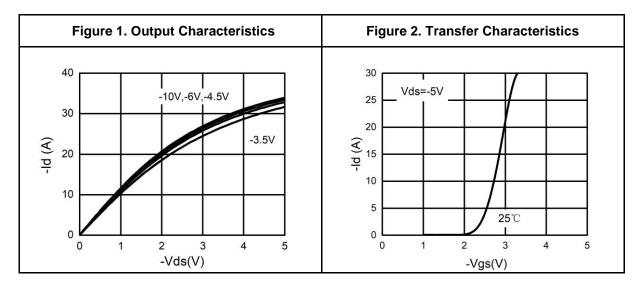
3) Switch Time Test Circuit

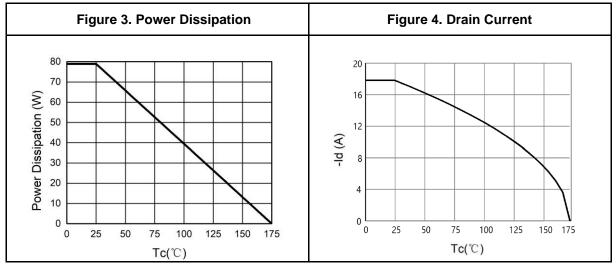


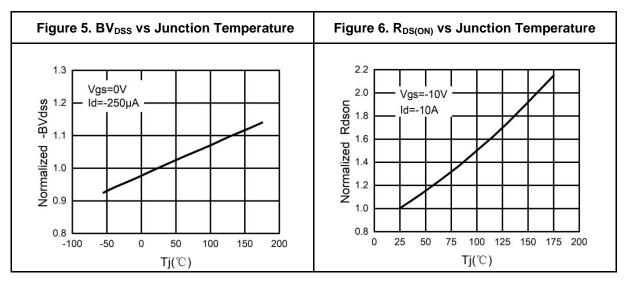




Typical Characteristics

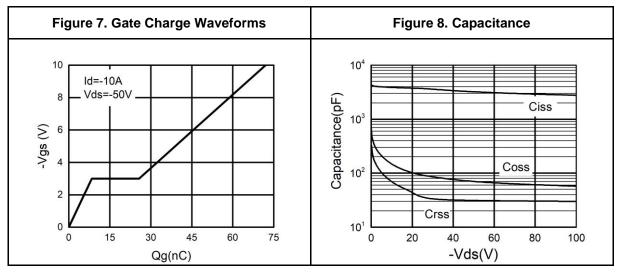


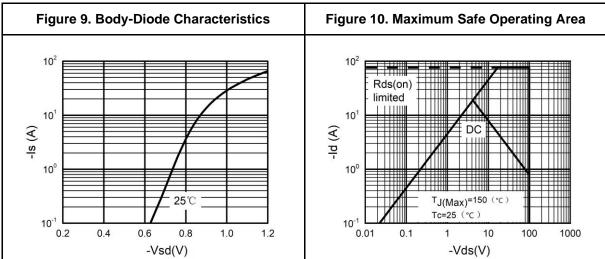






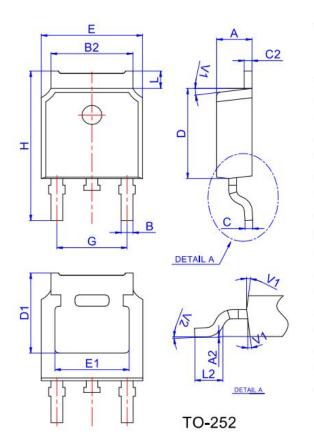
Typical Characteristics







TO-252 Package Information



	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
В	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
С	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF		0.209REF			
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
Н	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

AP18P10K





Revision History

Revision	Release	Remark
V1.0	2024/01/17	Initial Release

Disclaimer

The information given in this document describes the independent performance of the product, but similar performance is not guaranteed under other working conditions, and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Allpower assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which

requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.